



## IQS227AS/B DATASHEET

Single channel capacitive proximity  
and touch controller

The **IQS227AS/B** ProxSense® IC is a fully integrated Self Capacitive sensor with dual outputs (Touch and Proximity outputs).

### Features

- > Sub 2.5µA in Low Power Mode while sensing Proximity
- > **Automatic Tuning Implementation (ATI)** - Automatic tuning of sense electrode
- > **Internal Capacitor Implementation (ICI)** – reference capacitor on-chip
- > Supply voltage: 1.8V to 3.6V
- > Minimum external components
- > Data streaming option
- > Advanced on-chip digital signal processing
- > User selectable (OTP):
  - 4 Power Modes
  - IO sink / source
  - Time-out for stuck key
  - Output mode (Direct / Latch / Toggle)
  - Proximity and Touch Button sensitivity

**RoHS2**  
Compliant



### Applications

- > LCD, Plasma & LED TVs
- > GSM cellular telephones – On ear detection / touch keys
- > LED flashlights or headlamps
- > White goods and appliances
- > Office equipment, toys, sanitary ware
- > Flame proof, hazardous environment Human Interface Devices
- > Proximity detection enables backlighting activation
- > Wake-up from standby applications
- > Replacement for electromechanical switches
- > Find-In-The-Dark (FITD) applications
- > Automotive: Door pocket lighting, electric window control
- > GUI trigger on Proximity detected.

### Available options

T <sub>A</sub>	TSOT23-6	WLCSP-8	DFN-6
-20°C to 85°C	IQS227AS	-	-
-40°C to 85°C	IQS227B	IQS227B	IQS227B



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## List of Abbreviations

ATI	Automatic Tuning Implementation
BP	Boost Power Mode
CS	Counts (Number of Charge Transfers)
C <sub>s</sub>	Internal Reference Capacitor
EMI	Electromagnetic Interference
ESD	Electro-Static Discharge
FTB/EFT	(Electrical) Fast Transient Bursts
GND	Ground
HC	Halt Charge
LP	Low Power Mode
LTA	Long Term Average
ND	Noise Detect
THR	Threshold



## 1 Overview

The IQS227AS/B is a single channel capacitive proximity and touch controller with an internal voltage regular and reference capacitor ( $C_s$ ).

The IQS227AS/B devices have dedicated pin(s) for the connection of sense electrodes ( $C_x$ ) and output pins for proximity events on POUT and touch event on TOUT. The output pins can be configured for various output methods including a serial data streaming option on TOUT (1-wire protocol) or debug I<sup>2</sup>C.

Device configuration is determined by one time programmable (OTP) options.

The devices automatically track slow varying environmental changes via various filters,

detect noise and has an Automatic Tuning Implementation (ATI) to tune the device sense electrode(s). The IQS227AS/B is built on ProxSense® new low voltage platform ideal for battery application (down to 1.8V).

### 1.1 Applicability

All specifications, except where specifically mentioned otherwise, provided by this datasheet are applicable to the following ranges:

- > Temperature:
  - IQS227AS: -20°C to +85°C
  - IQS227B: -40°C to +85°C
- > Supply voltage ( $V_{DDHI}$ ): 1.8V to 3.6V

### 1.2 Analogue Functionality

The analogue circuitry measures the capacitance of a sense electrode attached to the  $C_x$  pin through a charge transfer process that is periodically initiated by the digital circuitry. The measuring process is referred to a conversion and consists of the discharging of reference capacitor and  $C_x$ , the charging of  $C_x$  and then a series of charge transfers from  $C_x$  to  $C_s$  until a trip voltage is reached. The number of charge transfers required to reach the trip voltage is referred to as the Counts (CS).

The capacitance measurement circuitry makes use of an internal  $C_s$  and voltage reference ( $V_{REF}$ ).

The analogue circuitry further provides functionality for:

- > Power on reset (POR) detection.
- > Reset detection.
- > Detection of a watch dog timer (WDT)



## 2 Packaging and Pin-out

### 2.1 IQS227AS/B

The IQS227AS is available in a TSOT23-6 package, the IQS227B is available in TSOT23-6 or WLCSP-8 package

#### 2.1.1 TSOT23-6 Pin-out

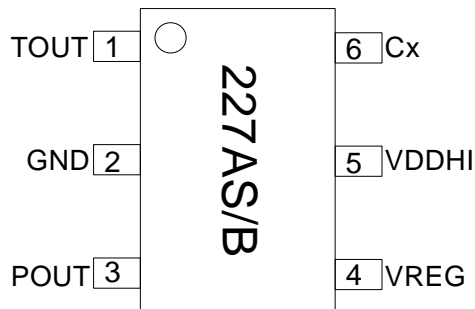


Figure 2.1: Pin-out of IQS227AS/B in TSOT23-6 package.

Table 2.1: Pin-out description.

IQS227AS/B			
Pin	Name	Type	Function
1	TOUT	Digital Out	Touch Output
2	GND	Ground	GND Reference
3	POUT	Digital Out	Proximity Output
4	VREG	Analogue Output	Internal Regulator Pin
5	VDDHI	Supply Input	Supply Voltage Input
6	CX	Analogue I/O	Sense Electrode



## 2.1.2 WLCSP-8 Pin-out

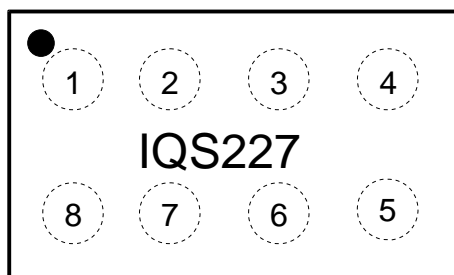


Figure 2.2 IQS227B 8-pin WLCSP

Table 2.2 8-pin WLCSP Pin-out Description

IQS227B 8-pin WLCSP			
Pin	Name	Type	Function
1	Cx	Sense electrode	Connect to conductive area intended for sensor
2	TOUT	Digital Out	Touch Output
3	VREG	Regulator output	Requires external capacitor
4	VSS	Signal GND	
5	INPUT	Digital Input	Floating input during runtime. Recommended: Connect to POUT
6	POUT	Digital Out	Proximity Output
7	VDDHI	Supply Input	Supply Voltage Input
8	PGM	Configuration pin	Connection for OTP programming. Floating input during runtime. Recommended: Connect to TOUT pin. Programming can still be performed using this pin, provided a diode is used. (See AZD026 – Configuration Tools Overview)



### 2.1.3 DFN-6 Pin-out

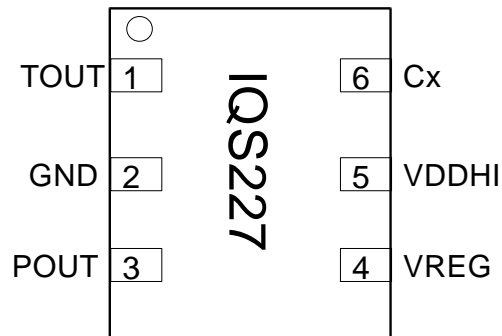


Figure 2.3: Pin-out of IQS227B in DFN-6 package.

Table 2.3: Pin-out description.

IQS227B 6-pin DFN			
Pin	Name	Type	Function
1	TOUT	Digital Out	Touch Output
2	GND	Ground	GND Reference
3	POUT	Digital Out	Proximity Output
4	VREG	Analogue Output	Internal Regulator Pin
5	VDDHI	Supply Input	Supply Voltage Input
6	CX	Analogue I/O	Sense Electrode





## 2.2 Schematic

### 2.2.1 TSOT23-6

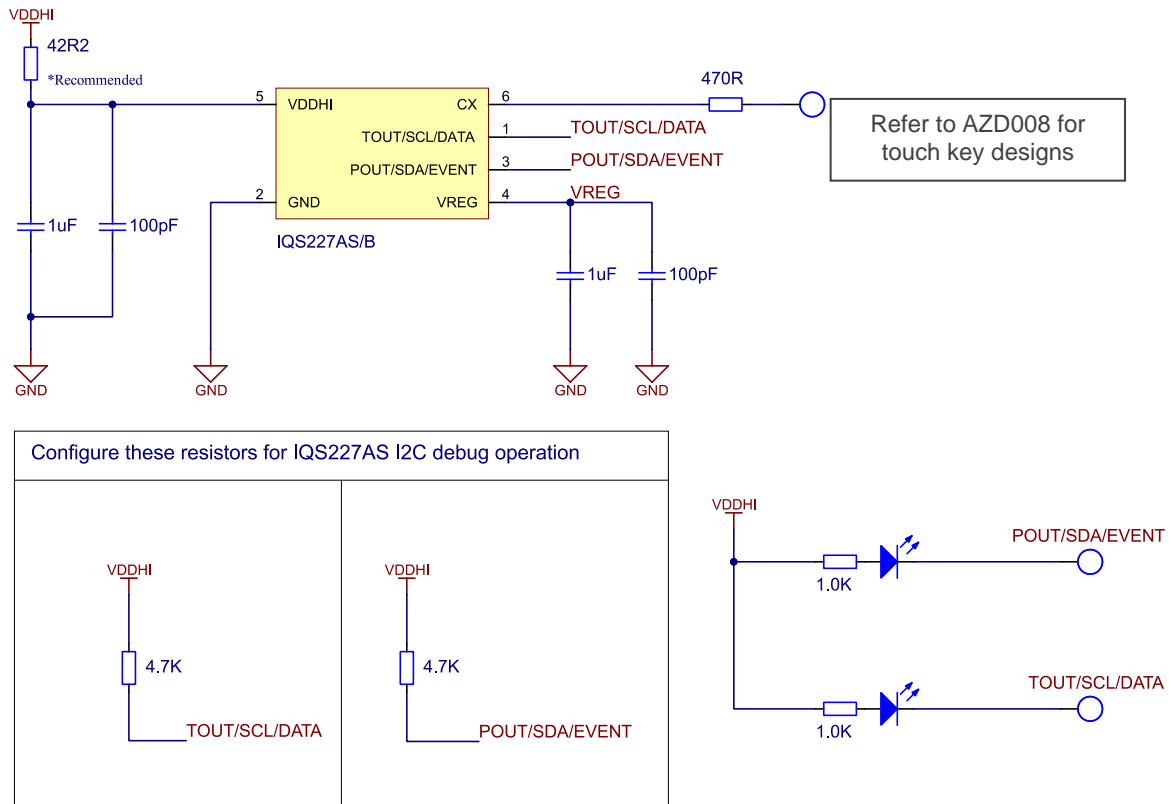


Figure 2.4: Typical application schematic of IQS227AS/B. 100pF capacitors are optional for added RF immunity. Place all decoupling capacitors (on VDDHI and VREG) as close to the IC as possible.

Where a system level ESD strike is found to cause the IC to go into ESD induced latch-up, it is suggested that the supply current to the IQS227 IC is limited by means of a series resistor that could limit the maximum supply current to the IC to <80mA.

### 2.2.2 WLCSP-8

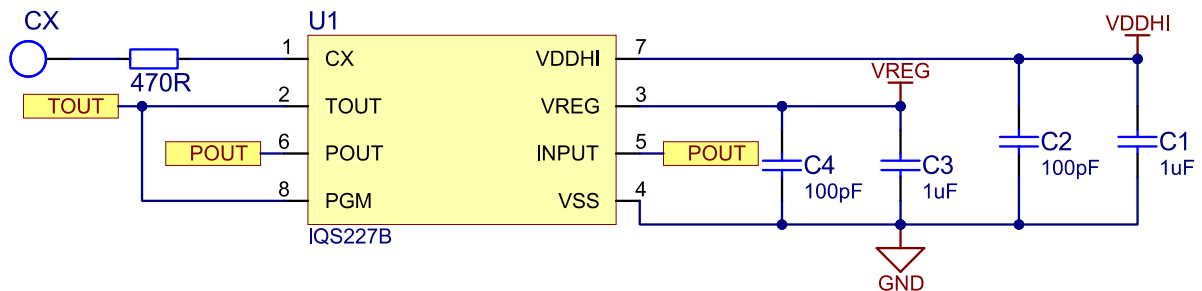


Figure 2.5 Typical application reference schematic of IQS227B WLCSP-8 Package. C2 & C3 are optional for added RF immunity



## 2.2.3 DFN-6

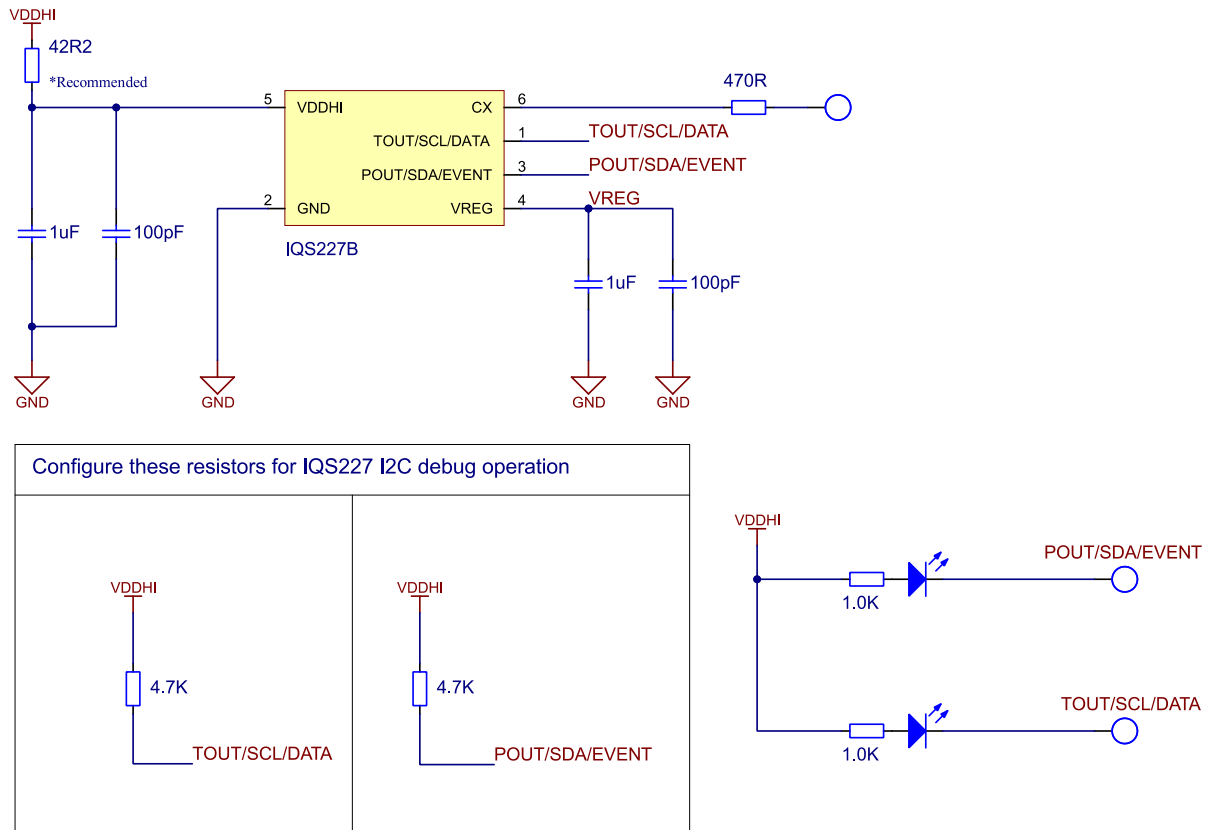


Figure 2.6 Typical application reference schematic of IQS227B DFN-6 Package. C2 & C3 are optional for added RF immunity



### 3 User Configurable Options

The IQS227AS/B provides One Time Programmable (OTP) user options (each option can be modified only once). The device is fully functional in the default state. OTP options are intended for specific applications.

The configuration of the device can be done on packaged devices or in-circuit. In-circuit configuration may be limited by values of external components chosen.

A number of standard device configurations are available. Azoteq can supply pre-configured devices for large quantities.

#### 3.1 Configuring of Devices

Azoteq offers a Configuration Tool (CT210) and accompanying software (USBProg.exe) that can be used to program the OTP user options for prototyping purposes. More details regarding the configuration of the device with the USBProg program is explained by application note: “AZD007 – USBProg Overview” which can be found on the Azoteq website.

Alternate programming solutions of the IQS227AS/B also exist. For further enquiries regarding this matter please contact Azoteq at ProxSenseSupport@azoteq.com or the local distributor

*Table 3.1: User Selectable Configuration Options: Bank 0 (0xC4H)*

T <sub>FUNC</sub>	P <sub>FUNC</sub>	LOGIC	T <sub>THR2</sub>	T <sub>THR1</sub>	T <sub>THR0</sub>	P <sub>THR1</sub>	P <sub>THR0</sub>
bit 7							bit 0
<b>Bank0: bit 7</b>	T <sub>FUNC</sub> : Touch Function 0 = Normal 1 = Toggle			<a href="#">Section 5.3</a>			
<b>Bank0: bit 6</b>	P <sub>FUNC</sub> : Proximity Function 0 = Normal 1 = Latch			<a href="#">Section 5.3</a>			
<b>Bank0: bit 5</b>	LOGIC: I/O's Output Logic Select 0 = Active Low 1 = Active High			<a href="#">Section 5.2</a>			
<b>Bank0: bit 4-2</b>	T <sub>THR</sub> : Touch Thresholds 000 = 72/256 001 = 8/256 010 = 24/256 011 = 48/256 100 = 96/256 101 = 128/256 110 = 160/256 111 = 192/256			<a href="#">Section 5.5</a>			
<b>Bank0: bit 1-0</b>	P <sub>THR</sub> : Proximity Thresholds 00 = 4 01 = 2 10 = 8 11 = 16			<a href="#">Section 5.4</a>			



Table 3.2: : User Selectable Configuration Options: Bank 1 – Full ATI (0xC5H)

t <sub>HALT1</sub>	t <sub>HALT0</sub>	~	~	~	BASE <sub>2</sub>	BASE <sub>1</sub>	BASE <sub>0</sub>
bit 7							bit 0
<b>Bank1: bit 7-6</b> t <sub>HALT</sub> : Halt times <a href="#">Section 5.13</a> 00 = 20 seconds 01 = 40 seconds 10 = Never 11 = Always (Prox on 40s)							
<b>Bank1: bit 5-3</b> Not used							
<b>Bank1: bit 2-0</b> BASE: Base Value <a href="#">Section 5.7</a> 000 = 200 001 = 50 010 = 75 011 = 100 100 = 150 101 = 250 110 = 300 111 = 500							

Table 3.3: User Selectable Configuration Options: Bank 1 – Partial ATI

t <sub>HALT1</sub>	t <sub>HALT0</sub>	MULT <sub>SENSE1</sub>	MULT <sub>SENSE0</sub>	MULT <sub>COMP3</sub>	MULT <sub>COMP2</sub>	MULT <sub>COMP1</sub>	MULT <sub>COMP0</sub>
bit 7							bit 0
<b>Bank1:7-6</b> t <sub>HALT</sub> : Halt times <a href="#">Section 5.13</a> 00 = 20 seconds 01 = 40 seconds 10 = Never 11 = Always (Prox on 40s)							
<b>Bank1: bit 5-4</b> MULT: Multiplier for Sensitivity <a href="#">Section 5.8</a> 00 = 1 01 = 2 10 = 3 11 = 4							
<b>Bank1: bit 3-0</b> MULT: Multiplier for Compensation <a href="#">Section 5.8</a> 0000 = 0 1111 = 15							



Table 3.4: User Selectable Configuration Options: Bank 2 (0xC6H)

STREAM	TRANS	COMMS	ND	Target	ATI	LP1	LP0
bit 7							bit 0
<b>Bank2: bit 7</b>	<b>STREAM:</b> Streaming Method 0 = 1-wire 1 = 2-wire (I <sup>2</sup> C)			<a href="#">Section 6.2</a>			
<b>Bank2: bit 6</b>	<b>TRANS:</b> Charge Transfer Frequency 0 = 512kHz 1 = 250kHz			<a href="#">Section 5.9</a>			
<b>Bank2: bit 5</b>	<b>COMMS:</b> Streaming 0 = Disabled 1 = Enabled			<a href="#">Section 6</a>			
<b>Bank2: bit 4</b>	<b>ND:</b> Noise Detect 0 = Disabled 1 = Enabled (1-wire comms only)			<a href="#">Section 5.11</a>			
<b>Bank2: bit 3</b>	<b>Target:</b> ATI target counts 0 = 1024 1 = 512			<a href="#">Section 5.10</a>			
<b>Bank2: bit 2</b>	<b>ATI:</b> ATI selection 0 = Full 1 = Partial			<a href="#">Section 5.12</a>			
<b>Bank2: bit 1-0</b>	<b>LP:</b> Low Power Modes 00 = BP (9ms) 01 = NP (128ms) 10 = LP1 (256ms) 11 = LP2 (512ms)			<a href="#">Section 5.6</a>			



## 4 Measuring capacitance using the *Charge Transfer* method

The *charge transfer* method of capacitive sensing is employed on the IQS227AS/B.

A charge cycle is used to take a measurement of the capacitance of the sense electrode (connected to Cx) relative to ground. It consists of a series of pulses charging Cx and discharging Cx to the reference capacitor, at the charge transfer frequency (FCX - refer to Section 8). The number of the pulses required to reach a trip voltage on the reference capacitor is referred to as **Count Value** (CS) which is the instantaneous capacitive measurement. The Counts (CS) are used to determine if either a physical contact or proximity event occurred (refer to section 5.13.1), based on the change in Counts (CS) detected. The typical values of CS, without a touch or proximity condition range between 650 and 1150 Counts, although higher and lower counts can be used based on the application requirements. With counts larger than +/-1150

the gain of the system may become too high causing unsteady operation.

The IQS227AS/B schedules a charge cycle every  $t_{\text{SAMPLE}}$  seconds to ensure regular samples for processing of results. The duration of the charge cycle is defined as  $t_{\text{CHARGE}}$ . (refer to 0) and varies according to the counts required to reach the trip voltage. Following the charge cycle other activities such as data streaming is completed (if in streaming mode), before the next charge cycle is initiated.

**Please note: Attaching a probe to the Cx pin will increase the capacitance of the sense plate and therefore  $C_s$ . This may have an immediate influence on the counts (decrease  $t_{\text{CHARGE}}$ ) and cause a proximity or touch event. After  $t_{\text{HALT}}$  seconds the system will adjust to accommodate for this change. If the total load on Cx, with the probe attached is still lower than the maximum Cx load the system will continue to function normally after  $t_{\text{HALT}}$  seconds with the probe attached.**

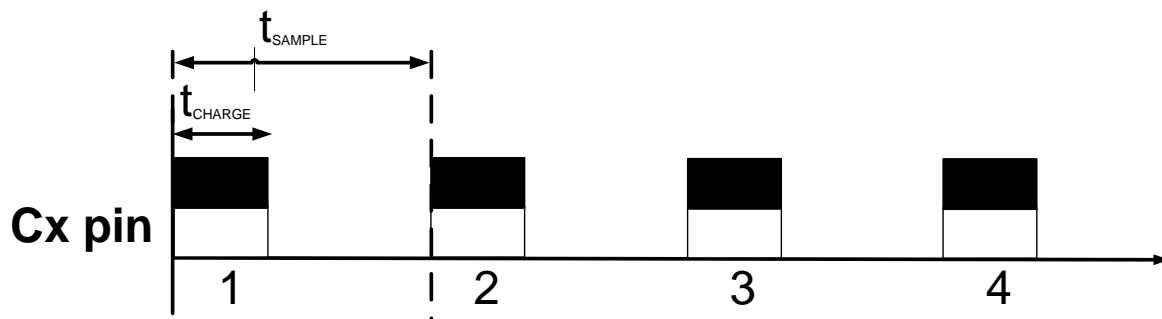


Figure 4.1: Charge cycles as can be seen on Cx.

## 5 Descriptions of User Options

This section describes the individual user programmable options of the IQS227AS/B in more detail.

User programmable options are programmed to One Time Programmable (OTP) fuse registers (refer to Section 3).

- > HIGH=Logical '1' and LOW=Logical '0'.
- > The following sections are explained with POUT and TOUT taken as 'Active LOW'.
- > The default is always where bits are set to 0.

Refer to section 0 for the sourcing and sinking capabilities POUT and TOUT. These pins are sourced from  $V_{\text{DDHI}}$  and will be turned HIGH (when active high) for a minimum time of  $t_{\text{HIGH}}$ , and LOW for a minimum time of  $t_{\text{LOW}}$  (when active low).

### Note:



## 5.1 Proximity / Touch Sensor

The IQS227AS/B provides a Proximity output on POUT and a Touch output on TOUT, and does not need to be configured.

## 5.2 Logic select for outputs

The logic used by the device can be selected as active HIGH or active LOW. The output pins, POUT and TOUT, will function based on this selection. The I/O's are push pull in both directions and does not require a pull-up resistor. When configured as Active High, the I/O's will remain high at POR until ATI has been completed. ATI times will vary based on the capacitive load on the sensor, but typically do not exceed 500ms.

### Configuration: Bank0 bit5

**LOGIC:** Output logic select -

Bit	Selection
0	Active Low
1	Active High

## 5.3 Output pin function

Various options for the function of the output pin(s) are available. These are selected as follow:

### Configuration: Bank0 bit7-6

**FUNC1:FUNC0** OUTPUT Pins' functions

Bit	Selection
00	POUT active, TOUT active
01	POUT latch, TOUT active
10	POUT active, TOUT toggle
11	POUT latch, TOUT toggle

### 5.3.1 Output function: Active

With a Proximity or Touch event, the output pin will change to LOW and stay LOW for as long as the event remains (see Figure 5.1 Also refer to the use of  $t_{\text{HALT}}$  section 5.13.1 that may cause the termination of the event.

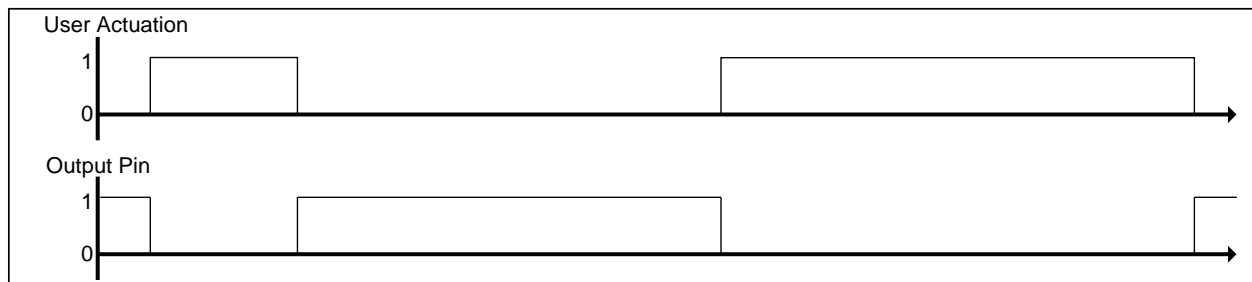


Figure 5.1: Active Mode Output Configuration

### 5.3.2 Output function: Latch (for $t_{\text{LATCH}}$ )

With a Proximity or Touch event, the output pin will latch LOW for  $t_{\text{LATCH}}$  seconds (4 seconds).

When the event terminates prior to  $t_{\text{LATCH}}$  the output pin will remain LOW.

When the event remains active longer than  $t_{\text{LATCH}}$  the output pin will remain LOW as long as the event remains active (see Figure 5.2)

When a subsequent event is made before the latch time (4 seconds) has passed, the timer will reset and the output will remain low for another duration of  $t_{\text{LATCH}}$  seconds (4 seconds). For more details see Figure 5.2.

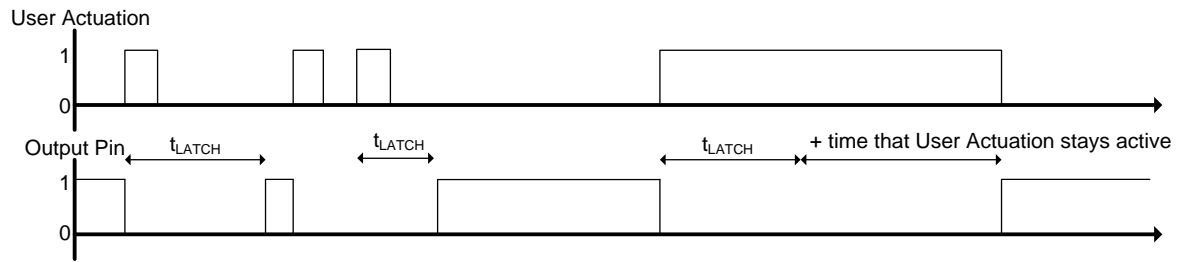


Figure 5.2: Latch Mode Output Configuration

### 5.3.3 Output function: Toggle

The output pin will toggle with every Proximity or Touch event occurring. Thus when an event

occurs and the output is LOW the output will become HIGH and when the output is HIGH the output will become LOW (see Figure 5.3)

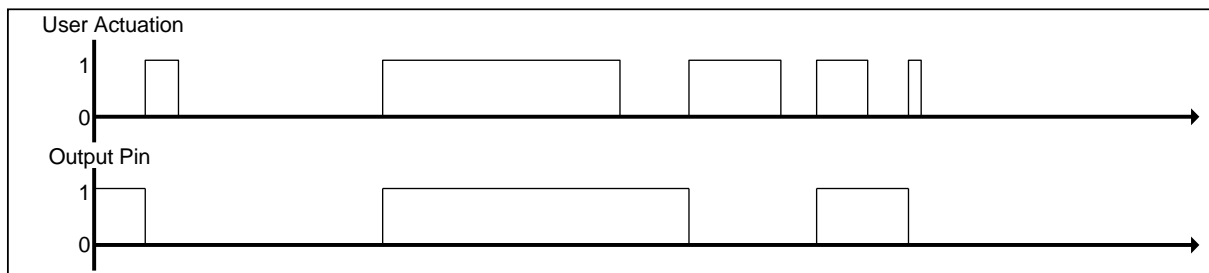


Figure 5.3: Toggle Mode Output Configuration

## 5.4 Proximity Threshold

The IQS227AS/B has 4 proximity threshold settings. The proximity threshold is selected by the designer to obtain the desired sensitivity and noise immunity. The proximity event is triggered based on the selected proximity threshold; the Counts (CS) and the LTA (Long Term Average). The threshold is expressed in terms of counts; the same as CS (refer to 0)

$$P_{THR} \leq LTA - CS$$

Where LTA is the Long Term Average (refer to 5.13.1)

## 5.5 Touch Threshold

The IQS227AS/B has 8 touch threshold settings. The touch threshold is selected by the designer to obtain the desired touch sensitivity. The touch threshold is expressed as a fraction of the LTA as follows:

$$T_{THR} = \frac{x}{256} \times LTA$$

The touch event is triggered based on  $T_{TH}$ , Counts (CS) and LTA. A touch event is

### Configuration: Bank0 bit1-0

**P<sub>THR1</sub>:P<sub>THR0</sub>** Proximity Thresholds

Bit	Selection
00	4
01	2 (Most sensitive)
10	8
11	16 (Least sensitive)

A proximity event is identified when for at least 6 consecutive samples the following equation holds:

identified when for at least 3 consecutive samples the following equation holds:

$$T_{THR} \leq LTA - CS$$

With lower average counts (therefore lower LTA) values the touch threshold will be lower and vice versa.





Configuration: [Bank0 bit4-2](#)

$T_{THR2}:T_{THR0}$ : Touch Thresholds	
Bit	Selection
000	72/256
001	8/256 (Most sensitive)
010	24/256
011	48/256
100	96/256
101	128/256
110	160/256
111	192/256 (Least sensitive)

## 5.6 Power Modes

The IQS227AS/B has four power modes specifically designed to reduce current consumption for battery applications.

The power modes are basically implemented around the occurrence of charge cycle every  $t_{SAMPLE}$  seconds (refer to Table 5.1). The fewer charge transfer cycles that need to occur per second the lower the [power consumption](#) (but decreased response time).

During Boost Power Mode (BP), charge cycles are initiated approximately every 9ms.

While in any power mode the device will zoom to BP whenever an existing count sample (CS) indicates a possible proximity or touch event. The device will remain in BP for  $t_{ZOOM}$  seconds and then return to the selected power mode. The Zoom function allows reliable detection of events with counts being produced at the BP rate.

Table 5.1: Power Mode configuration: Bank2 bit1-0

Bit	Power Mode timing	$t_{SAMPLE}$ (ms)
00	$t_{BP}$ (default)	BP (9ms)
01	$t_{NP}$	128
10	$t_{LP1}$	256
11	$t_{LP2}$	512



Figure 5.4: LP Modes: Charge cycles



## 5.7 Base Values

The sensitivity of the IQS227AS/B can be changed by adjusting the base value of the ATI algorithm, and as a result changing the compensation required to reach the target.

$$\text{Sensitivity} = \frac{\text{TARGET}}{\text{BASE}}$$

The target of the IQS227AS/B is fixed at 1000 counts.

**Configuration:** [Bank1 bit2-0](#)

**BASE:** Base Value Select -

Bit	Selection
000	200
001	50
010	75
011	100
100	150
101	250
110	300
111	500

## 5.8 Multipliers

When using partial ATI, the base value is set up using the multipliers. Compensation will still be added automatically to reach the target.

## 5.9 Charge Transfer

The charge transfer frequency of the IQS227AS/B is adjustable. Changing the transfer frequency will affect sensitivity and response rate. Two options are available:

**Configuration:** [Bank2 bit6](#)

**TRANS:** Charge Transfer Frequency

Bit	Selection
0	512kHz
1	250kHz

## 5.10 ATI Target Counts

The target of the ATI algorithm can be adjusted between 1024 (default) and 512 counts. When less sensitivity is required, the lower counts will also increase response rate.

**Configuration:** [Bank2 bit3](#)

**Target:** ATI Target Counts

Bit	Selection
0	1024
1	512

## 5.11 Noise Detect

**ND:** RF Noise Detection

The IQS227AS/B has RF Noise Detect (ND) functionality. If ND function is enabled, the IQS227AS/B is able to detect RF Noise on the TOUT pin. Further details on the working of this can be found in the Application Notes: AZD015 and AZD015b.

In extremely noise environments, and close proximity to RF noise sources, the noise detect of the IQS227AS/B can be enable to block false triggers. Proper layout guidelines should always be used before the need to use ND.

**Configuration:** [Bank2 bit4](#)

**ND:** Noise Detect

Bit	Selection
0	Disabled
1	Enabled

## 5.12 Enable Partial ATI

In some applications the startup time of the IQS227AS/B may be required to be decreased. This is possible by enabling partial ATI, if the multipliers required can be determined, and the compensation alone is adequate to account for environmental change.

**Configuration:** [Bank2 bit2](#)

**ATI:** Partial ATI

Bit	Selection
0	Disabled
1	Enabled

## 5.13 Filters used by the IQS227AS/B

The IQS227AS/B devices employ various signal processing functions that includes the execution of various filters as described below.

### 5.13.1 Long Term Average (LTA)

Capacitive touch devices detect changes in capacitance that are not always related to the



intended proximity or touch of a human. This is a result of changes in the environment of the sense plate and other factors. These changes need to be compensated for in various manners in order to reliably detect touch events and especially to detect proximity events. One mechanism the IQS227AS/B employs is the use of a Long Term Averaging filter (IIR type filter) which tracks slow changes in the environment (expressed as changes in the counts). The result of this filter is a Long Term Average (LTA) value that forms a dynamic reference used for various functions such as identification of proximity and touch events.

The LTA is calculated from the counts (CS). The filter only executes while no proximity or touch event is detected to ensure compensation only for environmental changes. However there may be instances where sudden changes in the environment or changes in the environment while a proximity or touch event has been detected cause the counts to drift away from the LTA. To compensate for these situations a Halt Timer ( $t_{\text{HALT}}$ ) has been defined.

The Halt Timer is started when a proximity or touch event occurs and when it expires the LTA filter is recalibrated. Recalibration causes  $\text{LTA} < \text{CS}$ , thus the disappearance of proximity or touch events (refer to 5.4 and 5.5).

The designer needs to select a Halt Timer value to best accommodate the required application.

**Configuration:** [Bank1 bit7-6](#)

$t_{\text{HALT1}}:t_{\text{HALT0}}$ : Halt time of Long Term Average	
Bit	Selection
00	20 seconds
01	40 seconds
10	NEVER
11	ALWAYS (Proximity on 40 seconds)

Notes:

- > The “NEVER” option indicates that the execution of the filters will never be halted.
- > With the ‘ALWAYS’ option and the detection of a proximity event the execution of the filter will be halted for only 40 seconds and with the detection of a touch event the execution of the filter will be halted as long as the touch condition applies.

Refer to Application note “AZD024 - Graphical Representation of the IIR Filter” for detail regarding the execution of the LTA filter.

### 5.13.2 IIR Raw Data filter

The extreme sensitivity of the IQS227AS/B makes it susceptible to external noise sources. This causes a decreased signal to noise (S/N) ratio, which could potentially cause false event detections.

Noise can also couple into the device as a result of poor PCB, sense electrode design and other factors influencing capacitive sensing devices.

In order to compensate for noise the IQS227AS/B uses an IIR filter on the raw data to minimize result of noise in the counts. This filter is implemented on all of the IQS227AS/B devices, and cannot be disabled.

## 6 Data Streaming Mode

The IQS227AS/B has the capability to stream data to a MCU. This provides the designer with the capability to obtain the parameters within the device in order to aid design into applications. Data streaming may further be used by an MCU to control events or further process results obtained from the IQS227AS/B devices. Data streaming is performed as a 1-wire data protocol on TOUT, OR set to I<sup>2</sup>C streaming (SDA on POUT, SCL on TOUT). Data Streaming can be enabled as indicated below:

**Configuration:** [Bank2 bit7](#)

<b>COMMS:</b> Data Streaming	
Bit	Selection
0	Disabled
1	Enabled

**Configuration:** [Bank2 bit5](#)

<b>STREAMING:</b> Data streaming mode	
Bit	Selection
0	1-Wire
1	I <sup>2</sup> C

Data streaming is initiated by the IQS227AS/B. When data streaming is enabled data is sent following each charge.

Figure 6.1 illustrates the communication protocol for initialising and sending data with the 1 wire communication protocol.



1. Communication is initiated by a START bit. Bit defined as a low condition for  $t_{\text{START}}$ .
2. Following the START bit, is a synchronisation byte ( $T_{\text{INIT}} = 0x\text{AA}$ ). This byte is used by the MCU for clock synchronisation.
3. Following  $T_{\text{INIT}}$  the data bytes will be sent. With short data streaming mode

enabled, 5 bytes of data will be sent, otherwise 8 bytes will be sent after each charge cycle.

4. Each byte sent will be preceded by a START bit and a STOP bit will follow every byte.
5. STOP bit indicated by taking pin 1 high. The STOP bit does not have a defined period.

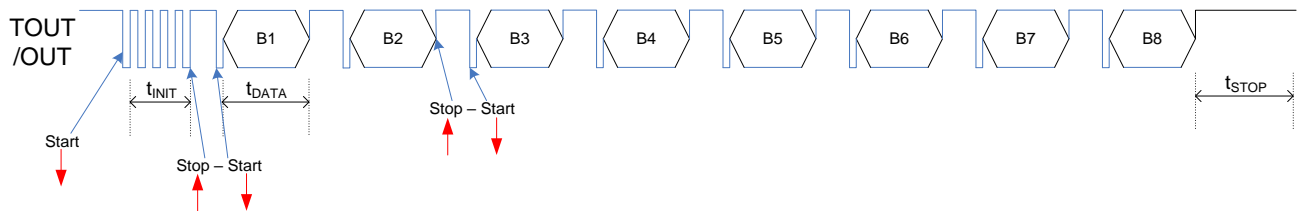


Figure 6.1: 1-wire data streaming mode

The following table defines the data streamed from the IQS227AS/B devices during the 1-wire streaming protocol.



Table 6.1: Byte Definitions for 1-Wire Data Streaming Mode

Byte (B)	Bit	Value
0		AA
1	7:0	CS High byte
2	15:8	CS Low byte
3	23:16	LTA High byte
4	31:24	LTA Low byte
5 Sys Flags	39	~
	38	~
	37	Active High
	36	Filter Halt
	35	LP active
	34	ATI Busy
	33	Noise Found
	32	In Zoom
6	47	Touch
	46	Proximity
	45	Multipliers
	44	Multipliers
	43	Multipliers
	42	Multipliers
	41	Multipliers
	40	Multipliers
7	55:48	Compensation
8	63:56	Counter

## 6.1 Event Mode

The IQS227AS/B has Event Mode implemented during 1-wire communication. This allows the MCU to monitor the POUT pin for status changes (proximity or touch made or released events) instead of capturing data continuously. Upon a status change, the IQS227AS/B will pull the POUT pin for low to indicate to the MCU to read data. The POUT pin will stay low for 1.6ms.

## 6.2 I<sup>2</sup>C

The IQS227AS/B also allows for I<sup>2</sup>C streaming for debugging. Data Streaming can be changed from 1-wire protocol to I<sup>2</sup>C as shown below:

### Configuration: Bank2 bit7: Streaming Mode

Bit	Selection
0	1-Wire Protocol
1	I <sup>2</sup> C Streaming

The Memory Map for the IQS227AS/B can be found in Appendix A.

The IQS227AS/B can communicate on an I<sup>2</sup>C compatible bus structure. Note that 4.7kΩ pull-up resistors should be placed on SDA and SCL.

The Control byte indicates the 7-bit device address (0x44H) and the Read/Write indicator bit.

## 7 Auto Tuning Implementation (ATI)

ATI is a sophisticated technology implemented in the latest generation ProxSense® devices that optimises the performance of the sensor in a wide range of applications and environmental conditions (refer to application note AZD0027 - Auto Tuning Implementation).

ATI makes adjustments through external reference capacitors (as required by most other solutions) to obtain optimum performance.

ATI adjusts internal circuitry according to two parameters, the ATI multiplier and the ATI compensation. The ATI multiplier can be viewed as a course adjustment and the ATI compensation as a fine adjustment.

The adjustment of the ATI parameters will result in variations in the counts and sensitivity. Sensitivity can be observed as the change in current sample as the result of a fixed change in sensed capacitance. The ATI parameters have been chosen to provide significant overlap. It may therefore be possible to select various combinations of ATI multiplier and ATI compensation settings to obtain the same count value. The sensitivity of the various options may however be different for the same count value.

### 7.1 Automatic ATI

The IQS227AS/B implements an automatic ATI algorithm. This algorithm automatically adjusts the ATI parameters to optimise the sensing electrodes connection to the device.



The device will execute the ATI algorithm whenever the device starts-up and when the counts are not within a predetermined range.

While the Automatic ATI algorithm is in progress this condition will be indicated in the streaming data and proximity and touch events cannot be detected. The device will only briefly remain in this condition and it will be entered only when relatively large shifts in the counts has been detected.

The automatic ATI function aims to maintain a constant count value, regardless of the capacitance of the sense electrode (within the maximum range of the device).

The effects of auto-ATI on the application are the following:

- > Automatic adjustment of the device configuration and processing parameters for a wide range of PCB and application designs to maintain an optimal configuration for proximity and touch detection.
- > Automatic tuning of the sense electrode at start-up to optimise the sensitivity of the application.
- > Automatic re-tuning when the device detects changes in the sensing electrodes capacitance to accommodate a large range of changes in the environment of the application that influences the sensing electrode.
- > Re-tuning only occurs during device operation when a relatively large sensitivity reduction is detected. This is to ensure smooth operation of the device during operation.
- > Re-tuning may temporarily influence the normal functioning of the device, but in most instances the effect will be hardly noticeable.
- > Shortly after the completion of the re-tuning process the sensitivity of a Proximity detection may be reduced slightly for a few seconds as internal filters stabilises.

Automatic ATI can be implemented so effectively due to:

- > Excellent system signal to noise ratio (SNR).
- > Effective digital signal processing to remove AC and other noise.

- > The very stable core of the devices.
- > Built in capability to accommodate a large range of sensing electrode capacitances.

## 7.2 IQS227AS/B Noise Immunity

The IQS227AS/B has advanced immunity to RF noise sources such as GSM cellular telephones, DECT, Bluetooth and WIFI devices. Design guidelines should however be followed to ensure the best noise immunity. The design of capacitive sensing applications can encompass a large range of situations but as a summary the following should be noted to improve a design:

- > A ground plane should be placed under the IC, except under the Cx line.
- > All the tracks on the PCB must be kept as short as possible.
- > The capacitor between  $V_{DDHI}$  and GND as well as between  $V_{REG}$  and GND, must be placed as close as possible to the IC.
- > A 100pF capacitor can be placed in parallel with the 1uF capacitor between  $V_{DDHI}$  and GND. Another 100pF capacitor can be placed in parallel with the 1uF capacitor between  $V_{REG}$  and GND.
- > When the device is too sensitive for a specific application a parasitic capacitor (typically up to 20pF) can be added between the Cx line and ground.
- > Proper sense electrode and button design principles must be followed.
- > Unintentional coupling of sense electrode to ground and other circuitry must be limited by increasing the distance to these sources or making use of the driven shield.
- > In some instances, a ground plane some distance from the device and sense electrode may provide significant shielding from undesired interference.
- > When then the capacitance between the sense electrode and ground becomes too large the sensitivity of the device may be influenced.

Note: ND input enable is a legacy input and is not recommended for use in new designs. The input has been desensitized by default and is not tested to trigger at a specific RF input power level





## 8 Electrical Specifications

### 8.1 Absolute Maximum Specifications

*Exceeding these maximum specifications may cause damage to the device.*

Operating temperature	IQS227AS IQS227B	-20°C to 85°C -40°C to 85°C
Supply Voltage ( $V_{DDHI} - V_{SS}$ )		3.6V
Maximum pin voltage ( $T_{OUT}$ , $P_{OUT}$ )		$V_{DDHI} + 0.3V$
Pin voltage ( $C_x$ )		1.7V
Minimum pin voltage ( $V_{DDHI}$ , $V_{REG}$ , $T_{OUT}$ , $P_{OUT}$ , $C_x$ )		$V_{SS} - 0.3V$
Minimum power-on slope		100V/s
HBM ESD protection ( $V_{DDHI}$ , $V_{REG}$ , $V_{SS}$ , $T_{OUT}$ , $P_{OUT}$ , $C_x$ )		8kV

### 8.2 General Characteristics

The IQS227AS/B devices are rated for supply voltages between 1.8V and 3.6V.

*Table 8.1: IQS227AS/B General Operating Conditions (Self)*

DESCRIPTION	Conditions	PARAMETER	MIN	TYP	MAX	UNIT
Supply voltage		$V_{DDHI}$	1.8	3.3	3.6	V
Internal regulator output	$1.8 \leq V_{DDHI} \leq 3.6$	$V_{REG}$	1.64	1.7	1.75	V
Boost operating current	$1.8 \leq V_{DDHI} \leq 3.6$	$I_{IQS227AS/B\_BP}$	119	128	135	$\mu A$
Normal operating current	$1.8 \leq V_{DDHI} \leq 3.6$	$I_{IQS227AS/B\_NP}$	4.7	6	7.6	$\mu A$
Low power operating current	$1.8 \leq V_{DDHI} \leq 3.6$	$I_{IQS227AS/B\_LP1}$	2.8	3.5	4.7	$\mu A$
Low power operating current	$1.8 \leq V_{DDHI} \leq 3.6$	$I_{IQS227AS/B\_LP2}$	1.75	<2.5 <sup>1</sup>	3	$\mu A$
$C_x$ pin capacitance	$1.8 \leq V_{DDHI} \leq 3.6$	$C_{CxLoad}$			120	pF

Charge Transfer Timings for low power modes are found in Section 5.6.

*Table 8.2: Start-up and shut-down slope Characteristics*

DESCRIPTION	Conditions	PARAMETER	MIN	MAX	UNIT
POR	$V_{DDHI}$ Slope $\geq 100V/s$	POR	0.3 <sup>2</sup>	1.7	V
VDDHI reset level	$V_{DDHI}$ Slope $\geq 100V/s$	$RESET_{VDDHI}$	N/A	1.7	V
VREG reset level	$V_{DDHI}$ Slope $\geq 100V/s$	$RESET_{VREG}$	N/A	1.58 <sup>3</sup>	V

<sup>1</sup> All low power current values arise from characterization done from (-)35°C to (+)85°C at 3.3V

<sup>2</sup> For a power cycle, ensure lowering VDDHI below the minimum value before ramping VDDHI past the maximum POR value

<sup>3</sup> Figure 2.4 Capacitors C1 & C3 should be chosen to comply with this specification



## 8.3 Output Characteristics

Table 8.3: TOUT Characteristics

Symbol	Description	V <sub>OH</sub>	Conditions	MIN	TYP	MAX	UNIT
I <sub>SOURCE</sub>	Output High voltage	0.9*VDDHI	V <sub>DDHI</sub> = 3.6V	~	~	TBD	mA
		0.9*VDDHI	V <sub>DDHI</sub> = 3.3V	~	10	~	
		0.9*VDDHI	V <sub>DDHI</sub> = 1.8V	TBD	~	~	
Symbol	Description	V <sub>OL</sub>	Conditions	MIN	TYP	MAX	UNIT
I <sub>SINK</sub>	Output Low voltage	0.1V	V <sub>DDHI</sub> = 3.6V			TBD	mA
		0.1V	V <sub>DDHI</sub> = 3.3V		10		
		0.1V	V <sub>DDHI</sub> = 1.8V	TBD			

Table 8.4: POUT Characteristics

Symbol	Description	VOH	Conditions	MIN	TYP	MAX	UNIT
I <sub>SOURCE</sub>	Output High voltage	0.9*VDDHI	V <sub>DDHI</sub> = 3.6V	~	~	TBD	mA
		0.9*VDDHI	V <sub>DDHI</sub> = 3.3V	~	10	~	
		0.9*VDDHI	V <sub>DDHI</sub> = 1.8V	TBD	~	~	
Symbol	Description	V <sub>OL</sub>	Conditions	MIN	TYP	MAX	UNIT
I <sub>SINK</sub>	Output Low voltage	0.1V	V <sub>DDHI</sub> = 3.6V			TBD	mA
		0.1V	V <sub>DDHI</sub> = 3.3V		10		
		0.1V	V <sub>DDHI</sub> = 1.8V	TBD			

Table 8.5: Combined Characteristics

Symbol	Description	VOH	Conditions	MIN	TYP	MAX	UNIT
I <sub>SOURCE</sub>	Output High voltage	0.9*VDDHI	V <sub>DDHI</sub> = 3.6V	~	~	TBD	mA
		0.9*VDDHI	V <sub>DDHI</sub> = 3.3V	~	17	~	
		0.9*VDDHI	V <sub>DDHI</sub> = 1.8V	TBD	~	~	
Symbol	Description	V <sub>OL</sub>	Conditions	MIN	TYP	MAX	UNIT
I <sub>SINK</sub>	Output Low voltage	0.1V	V <sub>DDHI</sub> = 3.6V			TBD	mA
		0.1V	V <sub>DDHI</sub> = 3.3V		20		
		0.1V	V <sub>DDHI</sub> = 1.8V	TBD			





## 8.4 Packaging Information

### 8.4.1 TSOT23-6

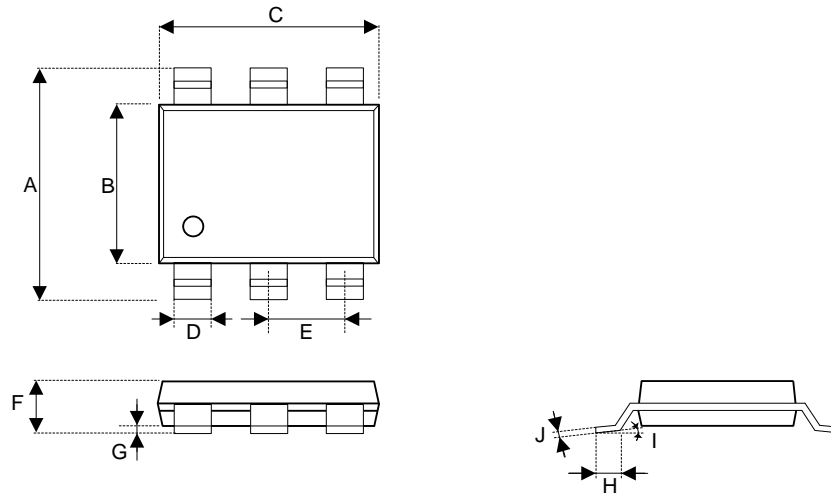


Figure 8.1 TSOT23-6 Packaging<sup>4</sup>

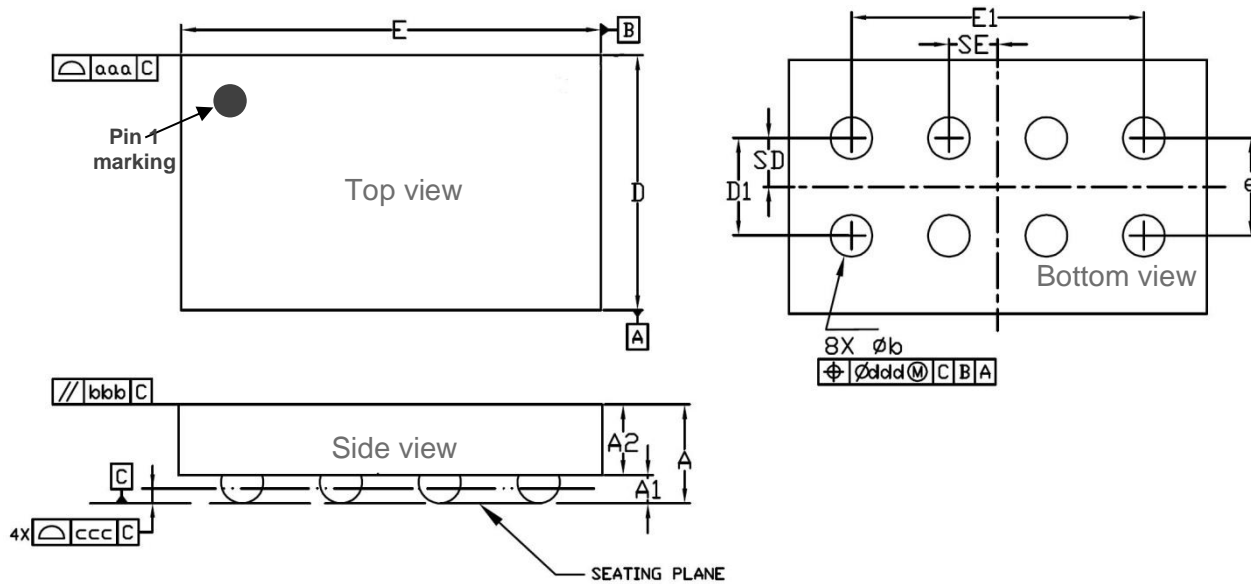
Table 8.6 TSOT23-6 Dimensions

Dimension	Min	Max
A	2.60mm	3.00mm
B	1.50mm	1.70mm
C	2.80mm	3.00mm
D	0.30mm	0.50mm
E	0.95 Basic	
F	0.84mm	1.00mm
G	0.00mm	0.10mm
H	0.30mm	0.50mm
I	0°	8°
J	0.03mm	0.20mm

<sup>4</sup> Drawing not on Scale



## 8.4.2 WLCSP-8

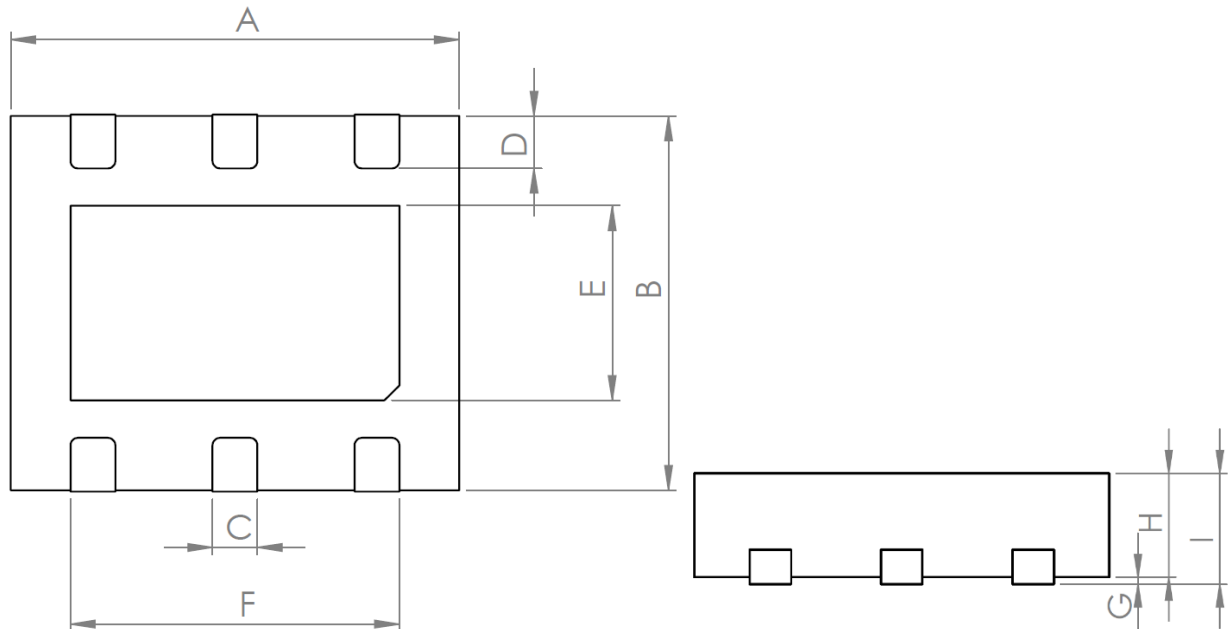


Dimensional Ref.			
REF.	Min.	Nom.	Max.
A	0.310	0.350	0.390
A1	0.085	0.100	0.115
A2	0.225	0.250	0.275
D	0.865	0.880	0.895
E	1.455	1.470	1.485
D1	0.300	0.350	0.400
E1	1.000	1.050	1.100
b	0.125	0.150	0.175
e	0.350 BSC		
SD	0.175 BSC		
SE	0.175 BSC		
Tol. of Form&Position			
aaa	0.10		
bbb	0.10		
ccc	0.05		
ddd	0.05		

Figure 8.2 IQS227B WLCSP-8 Dimensions (in mm)



### 8.4.3 DFN-6



DFN-6 Packaging

DFN-6 Dimensions

Dimension	Min	Max
A	3.00mm	3.00mm
B	2.50mm	2.50mm
C	0.30mm	0.30mm
D	0.35mm	0.35mm
E	1.30mm	1.30mm
F	2.20mm	2.20mm
G	0.05mm	0.05mm
H	0.75mm	0.75mm
I	0.80mm	0.80mm



## 8.5 Package MSL

**Moisture Sensitivity Level (MSL)** relates to the packaging and handling precautions for some semiconductors. The MSL is an electronic standard for the time period in which a moisture sensitive device can be exposed to ambient room conditions (approximately 30°C/85%RH see J-STD033C for more info) before reflow occur.

*Table 8.7:MSL*

Package	Level (duration)
TSOT23-6	MSL 1 (Unlimited at ≤30 °C/85% RH) Reflow profile peak temperature < 260 °C for < 30 seconds
WLCSP-8	Non-encapsulated device – not moisture sensitive Reflow profile peak temperature < 260 °C for < 30 seconds
DFN-6	MSL 1 (Unlimited at ≤30 °C/85% RH) Reflow profile peak temperature < 260 °C for < 30 seconds



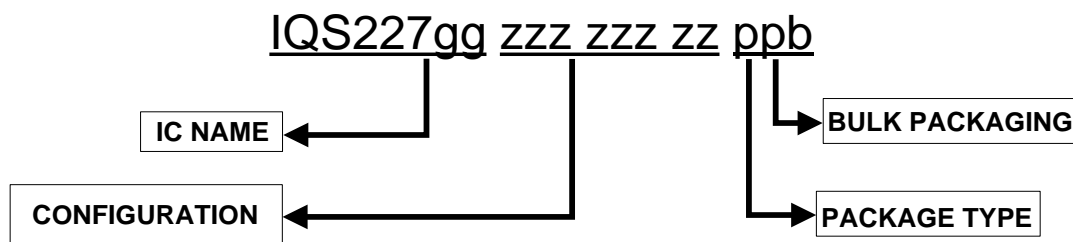
## 9 Datasheet and Part-number Information

### 9.1 Ordering Information

Orders will be subject to a MOQ (Minimum Order Quantity) of a full reel. Contact the official distributor for sample quantities. A list of the distributors can be found under the “Distributors” section of [www.azoteq.com](http://www.azoteq.com).

For large orders, Azoteq can provide pre-configured devices.

The Part-number can be generated by using USBProg.exe or the Interactive Part Number generator on the website.



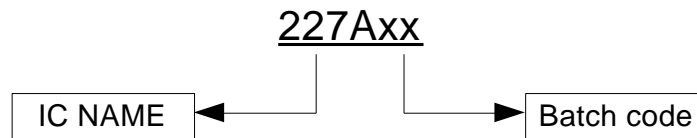
IC NAME	IQS227AS	=	IQS228 Self Capacitive
	IQS227B	=	IQS228 Self Capacitive
CONFIGURATION	zzz zzz zz	=	IC Configuration (hexadecimal)
PACKAGE TYPE	TS	=	TSOT23-6 package
	CS	=	WLCSP-8 package
	DN	=	DFN-6 package
BULK PACKAGING	R	=	Reel
			TSOT23-6 and WLCSP-8: 3000pcs/reel
			DFN-6: 6000pcs/reel
		=	MOQ = 1 reel (orders shipped as full reels)



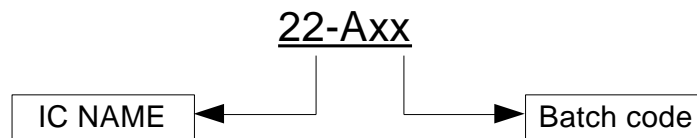
## 9.2 Device Marking – Top

### 9.2.1 TSOT23-6 Packaging Markings

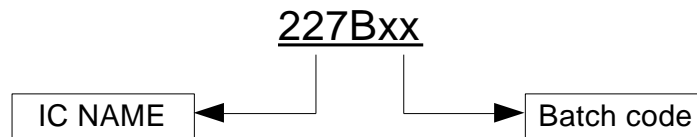
There are 2 marking versions in circulation for IQS227AS and IQS227B:



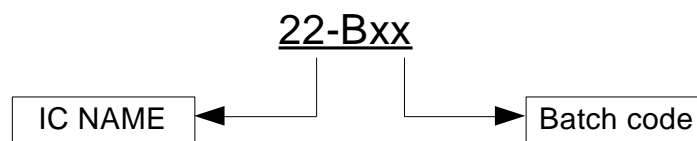
*Figure 9.1: First Marking Variant of IQS227AS*



*Figure 9.2: Second Marking Variant of IQS227AS*



*Figure 9.3: First Marking Variant of IQS227B*



*Figure 9.4: Figure 10 4 Second Marking Variant of IQS227B*

<b>IC NAME</b>	227A	=	IQS227AS Self Capacitive
	22-A	=	IQS227AS Self Capacitive
	227B	=	IQS227B Self Capacitive
	22-B	=	IQS227B Self Capacitive
<b>Batch Code</b>	xx	=	AA to ZZ



### 9.2.2 WLCSP-8 Package Markings

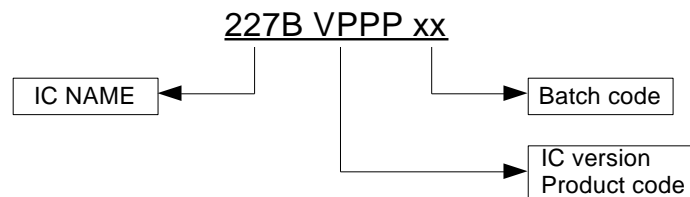


Figure 9.5 Top Marking of IQS227B WLCSP Package

IC NAME	227B	=	IQS227B Self Capacitive
Batch Code	xx	=	AA – ZZ
IC VERSION	V		
Product Code	PPP		

### 9.2.3 DFN-6 Package Markings

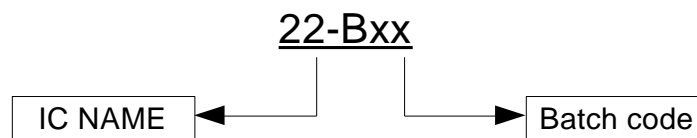


Figure 9.6 IQS227B DFN-6 Package Top Marking

IC NAME	22-B	=	IQS227B Self Capacitive
Batch Code	xx	=	AA to ZZ

### 9.3 Device Marking - Bottom

Some batches of TSOT23-6 IQS227AS/B will not have any bottom markings. These devices are configured after marking and may have variations in configuration – please refer to the reel label.

Other batches will display the configuration set on the chip on the bottom marking.





## 9.4 Tape & Reel Specification

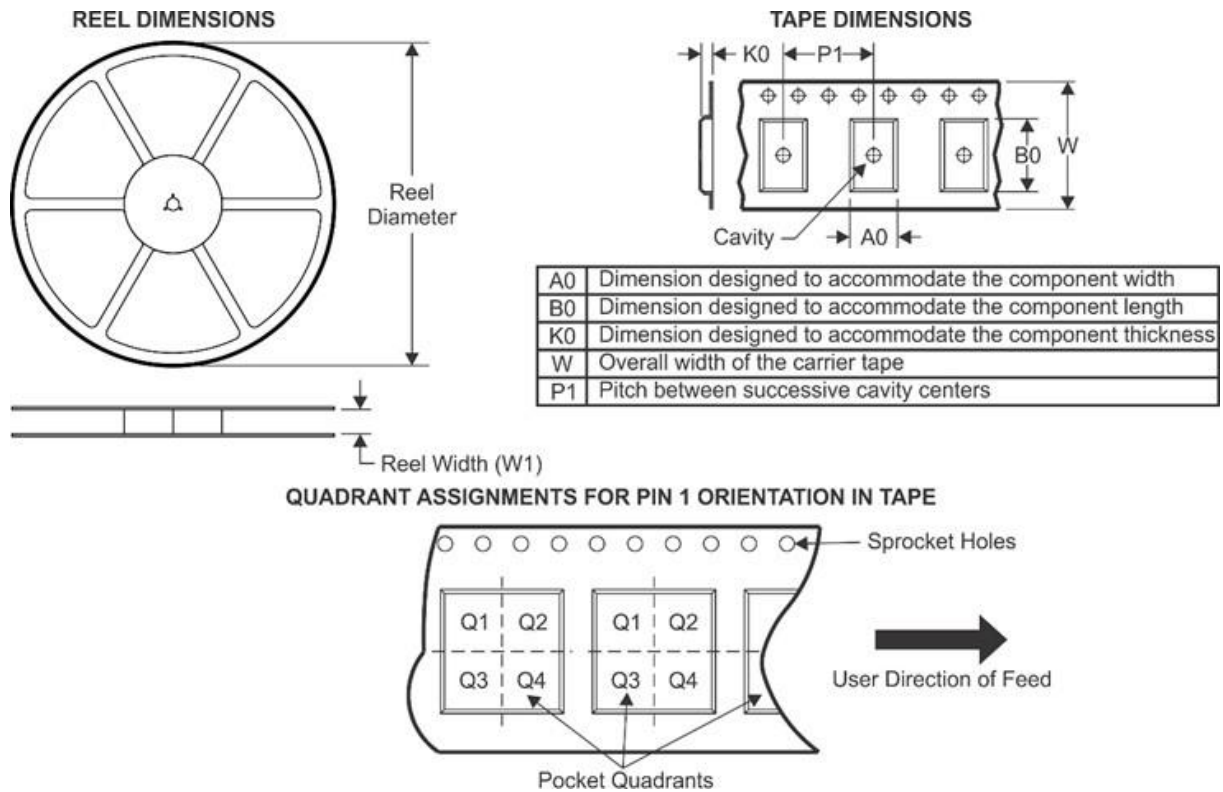


Figure 9.7: Tape and Reel Specification.

Table 9.1 Tape and Reel Dimensions

Device	Package Type	Package Drawing	Pins	QTY per reel	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
IQS227ASzzzzzzzzTSR	TSOT23/6	TSOT23-6	6	3000	178	9.5	3.1	3.1	1.3	4	8	Q3
IQS227BzzzzzzzzTSR	TSOT23/6	TSOT23-6	6	3000	178	9.5	3.1	3.1	1.3	4	8	Q3
IQS227BzzzzzzzzCSR	WLCSP8	WLCSP-8	8	3000	179	8.4	1	1.55	0.48	4	8	Q3
IQS227BzzzzzzzzDNR	DFN6	DFN-6	6	6000	330	12.4	2.8	3.3	1.2	4	12	Q1





## Appendix A. Memory Map

### Device Information

00H	Product Number (PROD_NR)								
	Bit	7	6	5	4	3	2	1	0
	Access	Value							
	R	39 (Decimal)							
	Note								

01H	Software Number (SW_NR)								
	Bit	7	6	5	4	3	2	1	0
	Access	Value							
	R	28 (Decimal)							
	Note								

#### [00H] PROD\_NR

The product number for the IQS227AS/B is 39 (decimal).

#### [01H] SW\_NR

The software version number of the device ROM can be read in this byte. The latest software version is 28 (decimal).

10H	System Flags (Sys_Flags)								
	Bit	7	6	5	4	3	2	1	0
	Access	Value							
	R	~ ~ Logic Halt LP ATI ND Zoom							
	Note								

#### [10H] SYSFLAGS0

Bit 7: **SYSTEM\_USE**

Bit 6: **SYSTEM\_USE**

Bit 5: **Logic:** Logic Output Indication

0 = Active Low

1 = Active High

Bit 4: **Halt:** Indicates Filter Halt status

0 = LTA not being Halted

1 = LTA Halted

Bit 3: **LP:** Low Power Mode

0 = Sample time BP

1 = Sample time LP



**Bit 2:** **ATI:** Status of automated ATI routine

0 = ATI is not busy

1 = ATI in progress

**Bit 1:** **ND:** This bit indicates the presence of noise interference.

0 = IC has not detected the presence of noise

1 = IC has detected the presence of noise

**Bit 0:** **ZOOM:** Zoom will indicate full-speed charging once an undebounced proximity is detected. In BP mode, this will not change the charging frequency.

0 = IC not zoomed in

1 = IC detected undebounced proximity and IC is charging at full-speed (BP)

31H		Status							
Access	Bit	7	6	5	4	3	2	1	0
	Value							Touch	Prox
	Note								
R									

#### [31H] Status

**Bit 1:** **Touch:** Touch indication bit.

0 = No Touch Detected

1 = Touch Event Detected

**Bit 0:** **Prox:** Proximity indication bit.

0 = No Proximity Detected

1 = Proximity Event Detected

42H		Counts_Hi (CS_H)							
Access	Bit	7	6	5	4	3	2	1	0
	Value	Counts High Byte							
	Note								
R									

43H		Counts_Low (CS_L)							
Access	Bit	7	6	5	4	3	2	1	0
	Value								
	Note								
R									



Access	Value	Counts Low Byte							
R	Note								

83H	LTA_Hi (LTA_H)								
	Bit	7	6	5	4	3	2	1	0
Access	Value	Long Term Average High Byte							
R	Note								

84H		LTA_Low (LTA_L)							
	Bit	7	6	5	4	3	2	1	0
Access	Value	Long Term Average Low Byte							
R	Note								

C4H		Fuse Bank 0 (FB_0)							
		Bit	7	6	5	4	3	2	1
Access	Value	See 0 for more details							
R	Note								

C5H		Fuse Bank 1 (FB_1)							
	Bit	7	6	5	4	3	2	1	0
Access	Value	See Table 3.2 for more details							
R	Note								

C6H		Fuse Bank 2 (FB_2)							
		Bit	7	6	5	4	3	2	1
Access	Value	See Table 3.4 for more details							



R	Note	
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C7H		Fuse Bank 3 (FB_3)							
Access R	Bit	7	6	5	4	3	2	1	0
	Value	Not used							
	Note								

C8H		DEFAULT_COMMS_POINTER							
Access R/W	Bit	7	6	5	4	3	2	1	0
	Value	(Beginning of Device Specific Data)							
	Default	10H							

#### **[C8H] Default Comms Pointer**

The value stored in this register will be loaded into the Comms Pointer at the start of a communication window. For example, if the design only requires the Proximity Status information each cycle, then the *Default Comms Pointer* can be set to ADDRESS '31H'. This would mean that at the start of each communication window, the comms pointer would already be set to the Proximity Status register, simply allowing a READ to retrieve the data, without the need of setting up the address.




## Appendix B. Contact Information

	USA	Asia	South Africa
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